



CALL FOR PAPERS SPECIAL ISSUE/SECTION

IEEE Transactions on Nanotechnology (TNANO) Special Section/Issue on the 1st International Conference on Memristive Materials, Devices & Systems

Extensive research on Memristor technologies, materials and devices has unveiled many interesting and promising applications in (nano)-electronics, bio and neuro-engineering, signal processing, sensors and beyond. Encouraged by the success of the First (1st) International Conference on Memristive Materials, Devices & Systems (MEMRISYS), IEEE Transactions on Nanotechnology (TNANO) will consider extended versions of papers presented at MEMRISYS 2017. Submitted manuscripts will undergo a full peer review process.

Authors are kindly requested to expand significantly the conference version to contain substantial new technical materials due to the restriction in duplicated publications and the competitive acceptance process.

Manuscripts for TNANO must be submitted on-line using the IEEE TNANO manuscript template and "Information for Authors", via the IEEE Manuscript Central found at <https://mc.manuscriptcentral.com/tnano>. On submission to TNANO, authors should select the "Special Issue" manuscript type instead of "Regular Paper." The authors should consider that manuscripts must focus on nanotechnology as reflected by technical contents and references.

Deadlines for TNANO Special Section/Issue:

Manuscript Submission:	July 31, 2017
First decision to authors:	September 31, 2017
Revision due (if necessary):	October 30, 2017
Final notification (acceptance/rejection):	November 30, 2017
Final manuscripts due:	December 31, 2017
Special section publication:	Early 2018

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